

SCS210AJ

SiC Schottky Barrier Diode

V_R	650V		
I _F	10A		
Q_C	15nC		

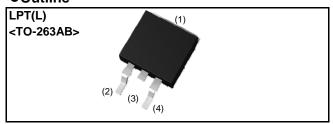
●Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

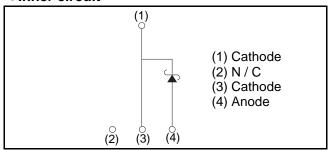
●Construction

Silicon carbide epitaxial planer type

●Outline



•Inner circuit



Packaging specifications

	Packaging	Embossed tape
	Reel size (mm)	330
Typo	Tape width (mm)	24
Type	Basic ordering unit (pcs)	1,000
Packing code Marking	TLL	
	Marking	SCS210AJ

● Absolute maximum ratings (Tj = 25°C)

Parameter	Symbol	Value	Unit	
Reverse voltage (repetitive peak)	V_{RM}	650	V	
Reverse voltage (DC)	V _R	650	V	
Continuous forward current	I _F	10* ¹	А	
		40* ²	А	
Surge no repetitive forward current	I _{FSM}	150* ³	А	
		31* ⁴	А	
Repetitive peak forward current	I _{FRM}	42* ⁵	А	
Total power dissipation	P _D	83* ⁶	W	
Junction temperature	Tj	175	°C	
Range of storage temperature	Tstg	-55 to +175	°C	

^{*1} Tc=137°C *2 PW=8.3ms sinusoidal,Tj=25°C

^{*3} PW=10μs square,Tj=25°C *4 PW=8.3ms sinusoidal, Tj=150°C

^{*5} Tc=100°C,Tj=150°C,Duty cycle=10% *6 Tc=25°C

●Electrical characteristics (Tj = 25°C)

Parameter	Symbol	Conditions	Values			Linit
Parameter		Conditions	Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =0.2mA	600	-	-	V
Forward voltage	V _F	I _F =10A,Tj=25°C	-	1.35	1.55	V
		I _F =10A,Tj=150°C	-	1.55	-	V
		I _F =10A,Tj=175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,Tj=25°C	-	2	200	μΑ
		V _R =600V,Tj=150°C	-	30	-	μΑ
		V _R =600V,Tj=175°C	-	70	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	365	-	pF
		V _R =600V,f=1MHz	-	37	-	pF
Total capacitive charge	Qc	V _R =400V,di/dt=350A/μs	-	15	-	nC
Switching time	tc	V _R =400V,di/dt=350A/μs	-	15	-	ns

●Thermal characteristics

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Thermal resistance	$R_{\text{th(j-c)}}$	-	-	1.5	1.8	°C/W

•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

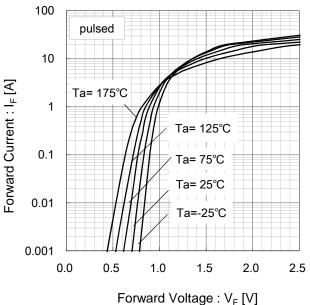
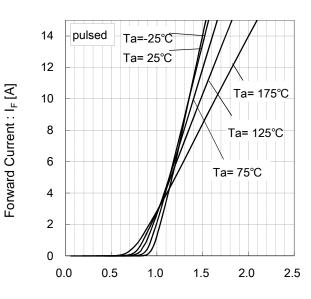


Fig.2 V_F - I_F Characteristics



Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

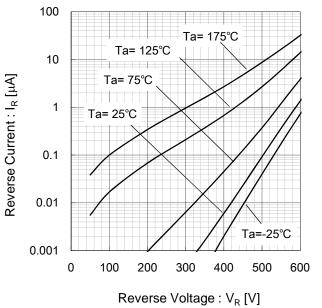
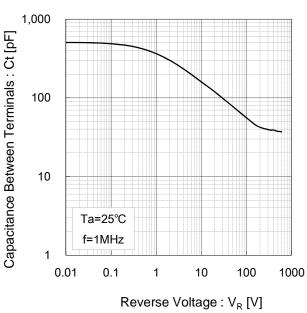


Fig.4 V_R-Ct Characteristics



•Electrical characteristic curves

Fig.5 Thermal Resistance vs. Pulse Width

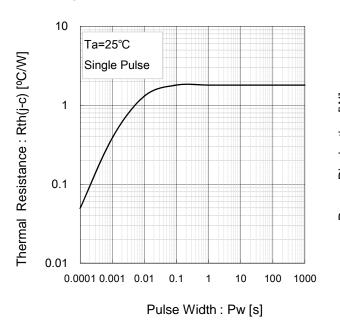


Fig.6 Power Dissipation

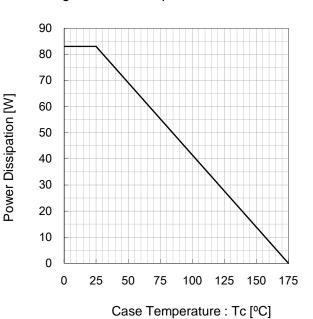


Fig.7 Derating Curve Ip-Tc

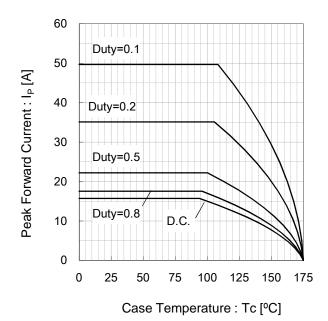
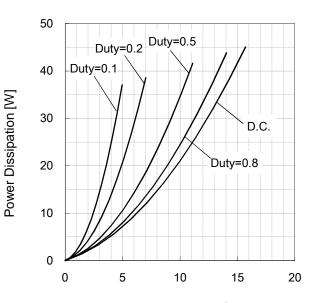


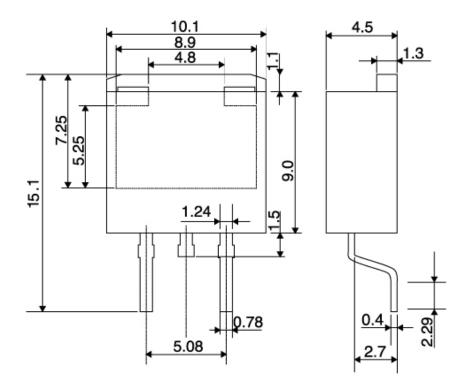
Fig.8 Io-Pf Characteristics



Average Rectified Forward Current : Io [A]

●Dimensions (Unit:mm)

LPT(L)



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